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#### **SDI Review Form 1.6**

Journal Name:	Physical Science International Journal
Manuscript Number:	2015_PSIJ_18362
Title of the Manuscript:	Diffusion and trapping of positrons in unimplanted and ion-implanted 3C-SiC and 6H-SiC
Type of the Article	Original Research Article

# **General guideline for Peer Review process:**

This journal's peer review policy states that  $\underline{NO}$  manuscript should be rejected only on the basis of 'lack of Novelty', provided the manuscript is scientifically robust and technically sound.

To know the complete guideline for Peer Review process, reviewers are requested to visit this link:

(http://www.sciencedomain.org/page.php?id=sdi-general-editorial-policy#Peer-Review-Guideline)

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## **PART 1:** Review Comments

	Reviewer's comment	Author's comment (if agreed with reviewer, correct the manuscript and highlight that part in the manuscript. It is mandatory that authors should write his/her feedback here)
Compulsory REVISION comments	Authors built the model to calculate the S-parameter in unimplanted 3C-SiC and 6H-SiC successfully. The theoretical results are closed to the experimental values. From these points, this manuscript is recommended to publish in this version.	
Minor REVISION comments		
Optional/General comments		

### **Reviewer Details:**

Name:	Anonymous
Department, University & Country	New York University, USA